6	first and second stages, one of which is for scanningly
7	moving the original and the other of which is for scanningly
8	moving the substrate;
9	measuring means for measuring a relative deviation
10	between said first stage and said second stage in a
11	predetermined direction other than the direction of scanning
12	movement; and
13	adjusting means for adjusting positional relationship
14	between the first stage and the second stage on the basis of
15	the measurement by said measuring means
1	170. An exposure method for the manufacture of
2	microdevices, in which a portion of a pattern of an original
3	is projected onto a substrate and in which the original and
4	the substrate are scanned in a timed relation such that the
5	pattern of the original is transferred to the substrate,
6	said method comprising the steps of:
7	providing first and second stages, one of which is for
8	scanningly moving the original and the other of which is for
9	scanningly moving the substrate;
10	measuring a relative deviation between the first stage
11	and the second stage in a predetermined direction other than
12	the scanning movement direction; and
13	adjusting positional relationship between the first
14	stage and the second stage on the basis of the measurement
15	in said measuring step